NSN 5961-01-588-0376

Diode Semiconductor Device - Page 1 of 1



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Between 1.000 inches and 1.300 inches

Overall Diameter:

Between 0.085 inches and 0.140 inches

End Application:

5999-01-529-7074: cca, bit, aircraft, ma

Mounting Method:

Terminal

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

27.0 breakdown voltage, dc

Current Rating Per Characteristic:

40.00 milliamperes reverse breakdown current, dc

Power Rating Per Characteristic:

1500.0 watts peak turn-on power dissipation

Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius ambient air

Product Name:

Semiconductor device, diode, silicon, voltage regulator

Special Features:

Unleaded or surface mounted; square end-cap diode

Terminal Type And Quantity:

2 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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